File G/courses/F2011/303H/303HF11hmrk2.doc RWN 09/11/11 303H Fall 2011

Homework 2 – due 09/20/11

1. 50 points (Diode characteristics)

For the diode 1N4007

- a) obtain a data sheet and attach
- b) Run Spice to obtain ID versus VD for −3V≤VD≤0.8V

2. 50 points (transistor biasing)

When only the signal behavior is of interest, often a circuit is shown without the biasing, as per the circuit shown below.

- a) Redraw the circuit to include biasing for both situations of
 - A1) two bias batteries with no additional resistors
 - A2) one battery with added resistors
- b) Assume IC=5milliA, beta forward =BF=80, forward Early voltage = VAF=200 .draw the small signal equivalent including $r\pi$, gm, ro.

